

**Features:**

- Isolated mounting base 4000V~
- Pressure contact technology with increased power cycling capability
- Space and weight saving

Typical Applications

- AC/DC Motor drives
- Various rectifiers
- DC supply for PWM inverter

V_{DSM}, V_{RSM}	V_{DRM}, V_{RRM}	Type & Outline
2700V	2600V	MFx110-26-216F3/216F3B
2900V	2800V	MFx110-28-216F3/216F3B
3100V	3000V	MFx110-30-216F3/216F3B
3300V	3200V	MFx110-32-216F3/216F3B
3500V	3400V	MFx110-34-216F3/216F3B
3700V	3600V	MFx110-36-216F3/216F3B

SYMBOL	CHARACTERISTIC	TEST CONDITIONS	$T_j(^{\circ}\text{C})$	VALUE			UNIT
				Min	Type	Max	
$I_{T(AV)}$	Mean on-state current	180° half sine wave 50Hz Single side cooled, $T_c=85^{\circ}\text{C}$	125			110	A
$I_{T(RMS)}$	RMS on-state current					173	A
I_{DRM} I_{RRM}	Repetitive peak current	at V_{DRM} at V_{RRM}	125			20	mA
I_{TSM}	Surge on-state current	10ms half sine wave	125			2.1	kA
I^2t	I^2t for fusing coordination	$V_R=60\%V_{RRM}$				22	$\text{A}^2\text{s}\cdot 10^3$
V_{TO}	Threshold voltage		125			1.15	V
r_T	On-state slope resistance					2.88	$\text{m}\Omega$
V_{TM}	Peak on-state voltage	$I_{TM}=330\text{A}$	25			2.68	V
dv/dt	Critical rate of rise of off-state voltage	$V_{DM}=67\%V_{DRM}$	125			800	$\text{V}/\mu\text{s}$
di/dt	Critical rate of rise of on-state current	Gate source 1.5A $t_r \leq 0.5\mu\text{s}$ Repetitive	125			100	$\text{A}/\mu\text{s}$
I_{GT}	Gate trigger current	$V_A=12\text{V}$, $I_A=1\text{A}$	25	30		150	mA
V_{GT}	Gate trigger voltage			0.8		2.5	V
I_H	Holding current			10		200	mA
V_{GD}	Non-trigger gate voltage	$V_{DM}=67\%V_{DRM}$	125	0.2			V
$R_{th(j-c)}$	Thermal resistance Junction to case	Single side cooled per chip				0.19	$^{\circ}\text{C}/\text{W}$
$R_{th(c-h)}$	Thermal resistance case to heat sink	Single side cooled per chip				0.15	$^{\circ}\text{C}/\text{W}$
V_{iso}	Isolation voltage	50Hz, R.M.S, $t=1\text{min}$, $I_{iso}: 1\text{mA}(\text{MAX})$		4000			V
F_m	Terminal connection torque (M6)				6.0		N·m
	Mounting torque (M6)				6.0		N·m
T_{vj}	Junction temperature			-40		125	$^{\circ}\text{C}$
T_{stg}	Stored temperature			-40		125	$^{\circ}\text{C}$
W_t	Weight				320		g
Outline	216F3、216F3B						

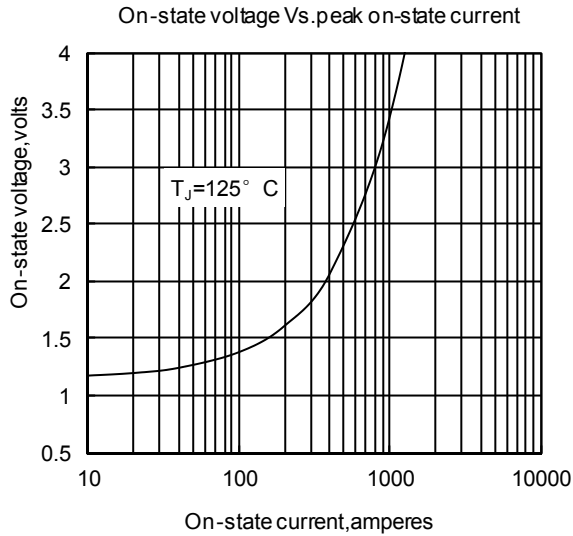


Fig. 1

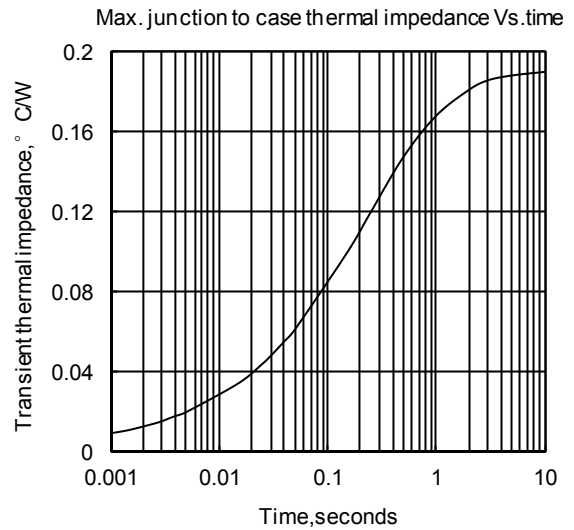


Fig. 2

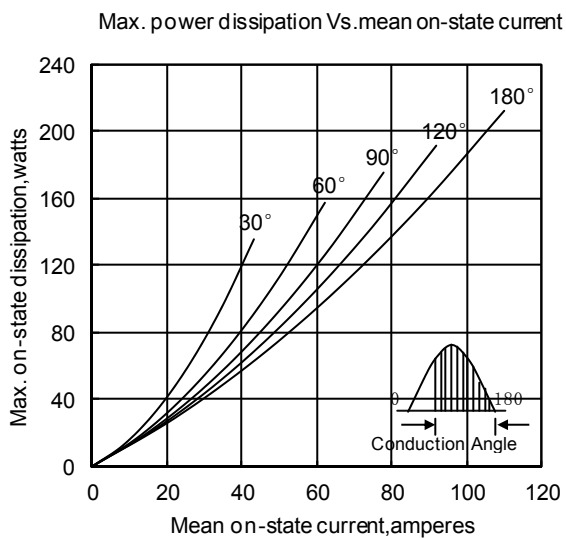


Fig. 3

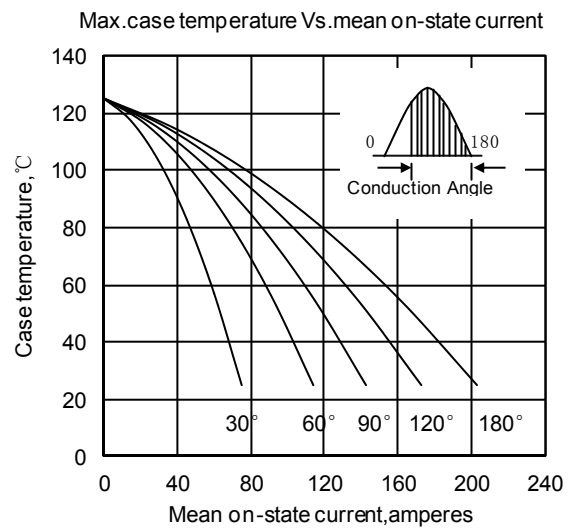


Fig. 4

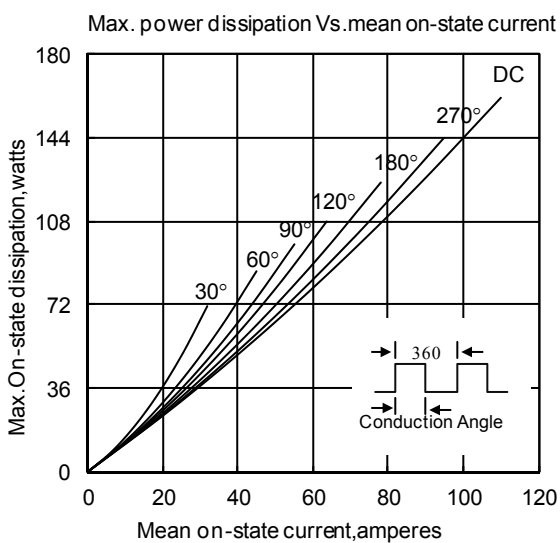


Fig. 5

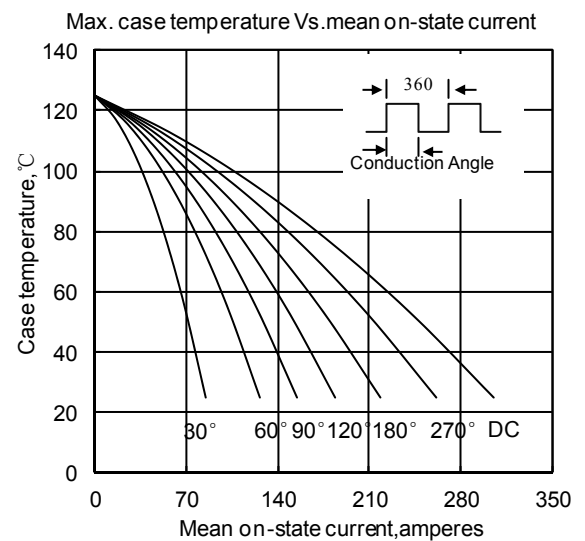


Fig. 6

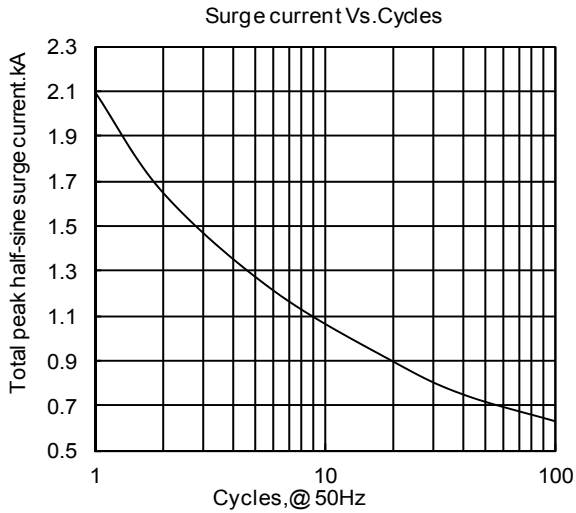


Fig. 7

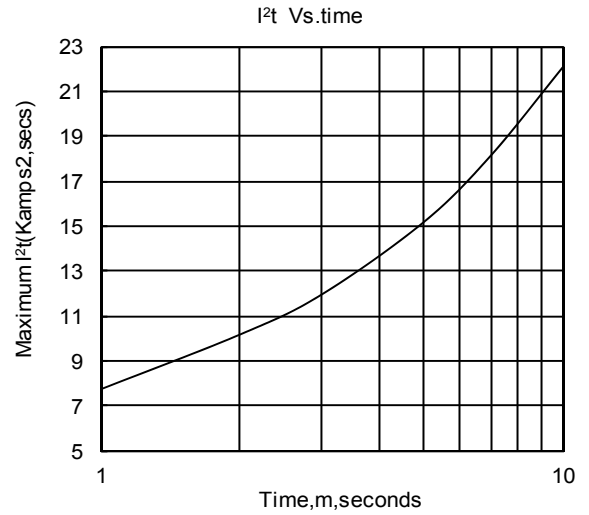


Fig. 8

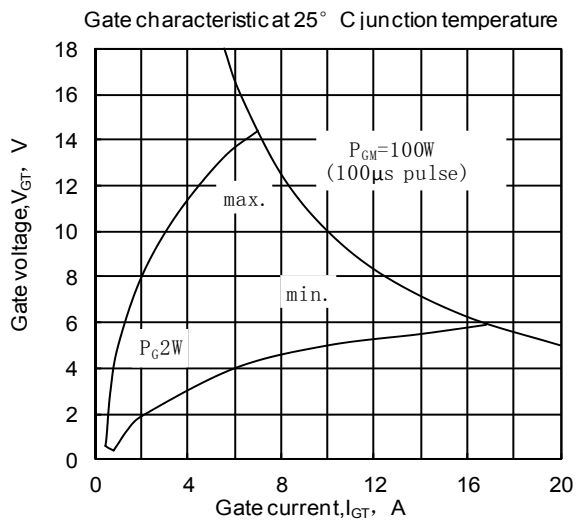


Fig. 9

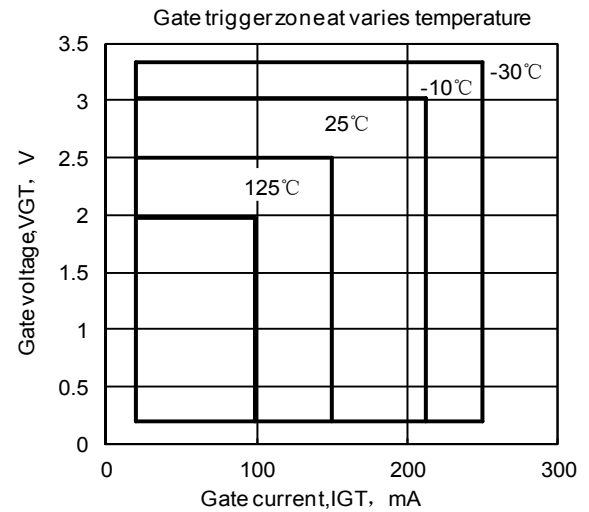
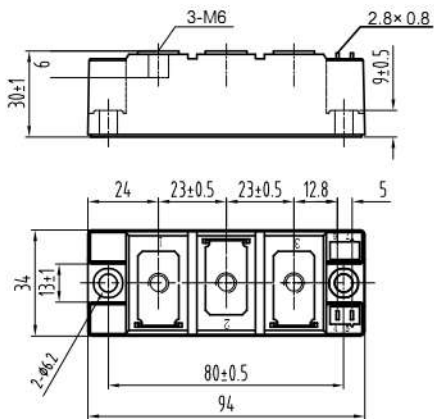


Fig. 10

Outline



216F3: 4 is Gate



216F3B: 5 is Gate

